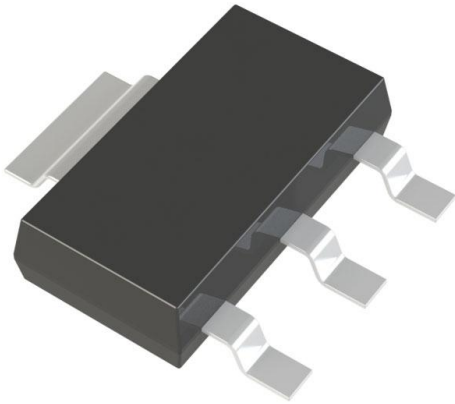


DZT751-13 Datasheet

www.digi-electronics.com



<https://www.DiGi-Electronics.com>

DiGi Electronics Part Number	DZT751-13-DG
Manufacturer	Diodes Incorporated
Manufacturer Product Number	DZT751-13
Description	TRANS PNP 60V 3A SOT223-3
Detailed Description	Bipolar (BJT) Transistor PNP 60 V 3 A 145MHz 1 W Surface Mount SOT-223-3



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.

Purchase and inquiry

Manufacturer Product Number:

DZT751-13

Series:

-

Transistor Type:

PNP

Voltage - Collector Emitter Breakdown (Max):

60 V

Current - Collector Cutoff (Max):

100nA (ICBO)

Power - Max:

1 W

Operating Temperature:

-55°C ~ 150°C (TJ)

Package / Case:

TO-261-4, TO-261AA

Base Product Number:

DZT751

Manufacturer:

Diodes Incorporated

Product Status:

Obsolete

Current - Collector (Ic) (Max):

3 A

Vce Saturation (Max) @ Ib, Ic:

600mV @ 300mA, 3A

DC Current Gain (hFE) (Min) @ Ic, Vce:

100 @ 500mA, 2V

Frequency - Transition:

145MHz

Mounting Type:

Surface Mount

Supplier Device Package:

SOT-223-3

Environmental & Export classification

RoHS Status:

ROHS3 Compliant

REACH Status:

REACH Unaffected

HTSUS:

8541.29.0075

Moisture Sensitivity Level (MSL):

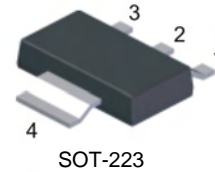
1 (Unlimited)

ECCN:

EAR99

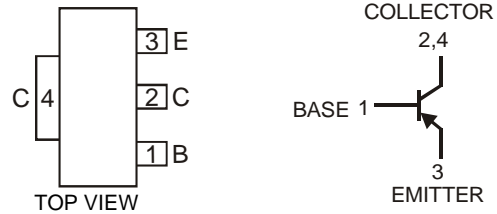
Features

- Epitaxial Planar Die Construction
- Complementary NPN Type Available (DZT651)
- Ideally Suited for Automated Assembly Processes
- Ideal for Medium Power Switching or Amplification Applications
- **Lead Free By Design/RoHS Compliant (Note 1)**
- **"Green" Device (Note 2)**



Mechanical Data

- Case: SOT-223
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish – Matte Tin annealed over Copper Leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208
- Marking & Type Code Information: See Page 4
- Ordering Information: See Page 4
- Weight: 0.115 grams



Schematic and Pin Configuration

Maximum Ratings @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-80	V
Collector-Emitter Voltage	V_{CEO}	-60	V
Emitter-Base Voltage	V_{EBO}	-5	V
Continuous Collector Current	I_C	-3	A
Peak Pulse Collector Current	I_{CM}	-6	A

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation @ $T_A = 25^\circ\text{C}$	P_D	1 (Note 3) 2 (Note 4)	W
Thermal Resistance, Junction to Ambient Air (Note 3) @ $T_A = 25^\circ\text{C}$	$R_{\theta JA}$	125	$^\circ\text{C/W}$
Operating and Storage Temperature Range	T_j, T_{STG}	-55 to +150	$^\circ\text{C}$

- Notes:
1. No purposefully added lead.
 2. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
 3. Device mounted on FR-4 PCB, pad layout as shown on last page or in Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>, or on page 4 of this data sheet.
 4. Device mounted on Polyimide PCB with 1.8cm² copper area.



Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 5)						
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	-80	—	—	V	$I_C = -100\mu\text{A}, I_E = 0$
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	-60	—	—	V	$I_C = -10\text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	-5	—	—	V	$I_E = -100\mu\text{A}, I_C = 0$
Collector Cutoff Current	I_{CBO}	—	—	-0.1	μA	$V_{CB} = -60\text{V}, I_E = 0$
Emitter Cutoff Current	I_{EBO}	—	—	-0.1	μA	$V_{CB} = -60\text{V}, I_E = 0, T_A = 100^\circ\text{C}$
ON CHARACTERISTICS (Note 5)						
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	—	-0.08	-0.3	V	$I_C = -1\text{A}, I_B = -100\text{mA}$
		—	-0.2	-0.6	V	$I_C = -3\text{A}, I_B = -300\text{mA}$
Base-Emitter Saturation Voltage	$V_{BE(SAT)}$	—	-0.9	-1.25	V	$I_C = -1\text{A}, I_B = -100\text{mA}$
Base-Emitter Turn-On Voltage	$V_{BE(ON)}$	—	-0.8	-1	V	$V_{CE} = -2\text{V}, I_C = -1\text{A}$
DC Current Gain	h_{FE}	70	200	—	—	$V_{CE} = -2\text{V}, I_C = -50\text{mA}$
		100	180	300	—	$V_{CE} = -2\text{V}, I_C = -500\text{mA}$
		80	160	—	—	$V_{CE} = -2\text{V}, I_C = -1\text{A}$
		40	140	—	—	$V_{CE} = -2\text{V}, I_C = -2\text{A}$
AC CHARACTERISTICS						
Transition Frequency	f_T	100	145	—	MHz	$V_{CE} = -5\text{V}, I_C = -100\text{mA}, f = 100\text{MHz}$
Output Capacitance	C_{obo}	—	—	30	pF	$V_{CB} = -10\text{V}, f = 1\text{MHz}$
Switching Times	t_{on}	—	45	—	ns	$V_{CC} = -10\text{V}, I_C = -500\text{mA}$
	t_{off}	—	200	—	ns	$I_{B1} = I_{B2} = -50\text{mA}$

Notes: 5. Pulse Test: Pulse width $\leq 300\mu\text{s}$. Duty cycle $\leq 2.0\%$.

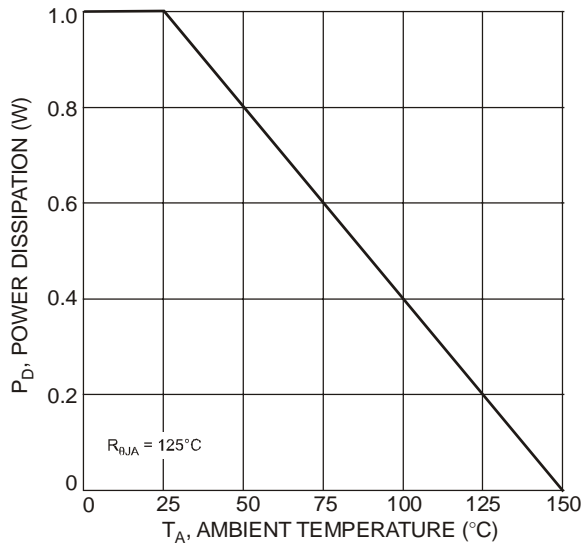


Fig. 1 Power Dissipation vs. Ambient Temperature (Note 3)

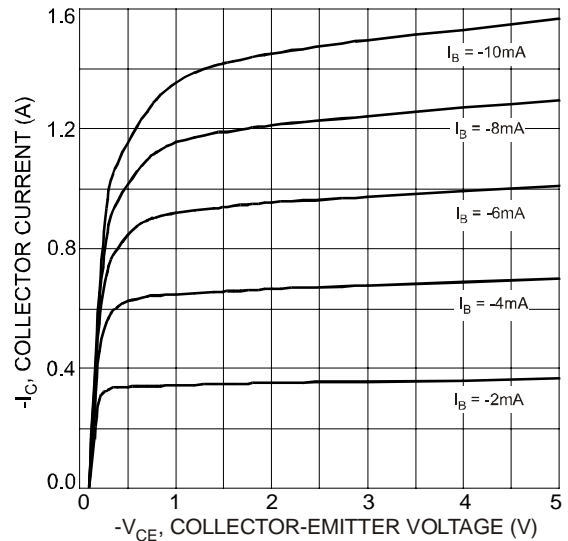


Fig. 2 Typical Collector Current vs. Collector-Emitter Voltage



NEW PRODUCT

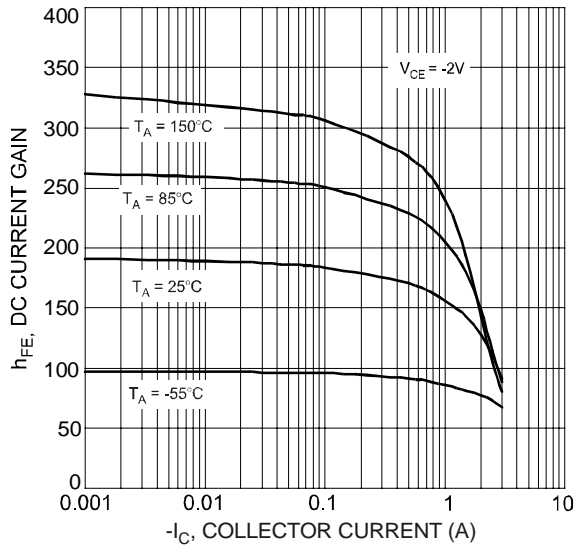


Fig. 3 Typical DC Current Gain vs. Collector Current

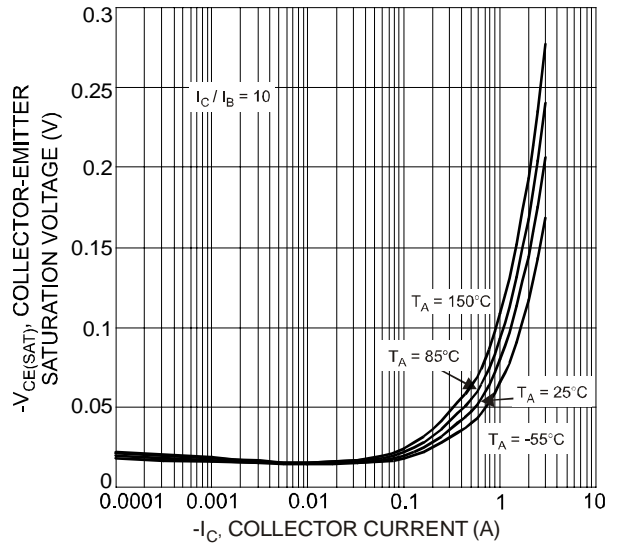


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

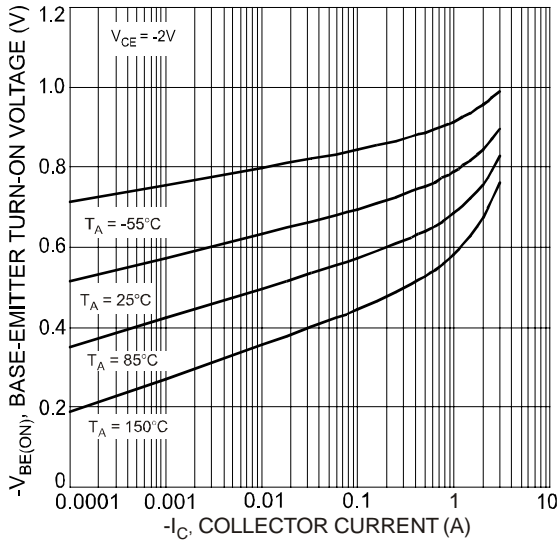


Fig. 5 Typical Base-Emitter Turn-On Voltage vs. Collector Current

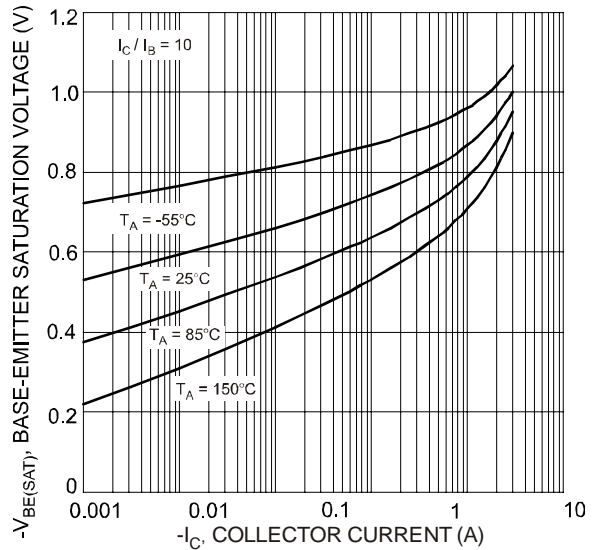


Fig. 6 Typical Base-Emitter Saturation Voltage vs. Collector Current

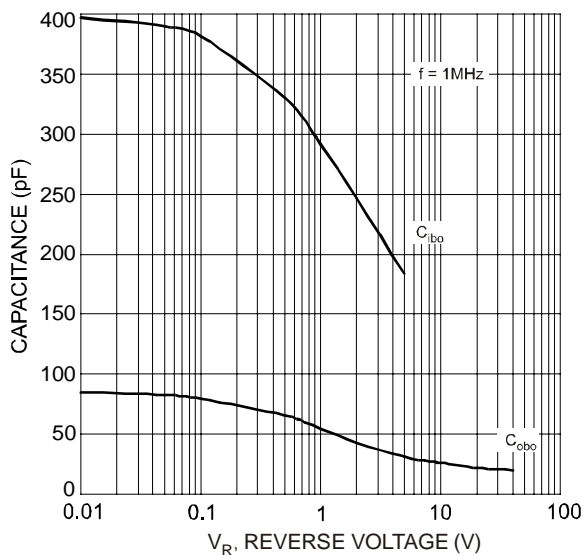


Fig. 7 Typical Capacitance Characteristics

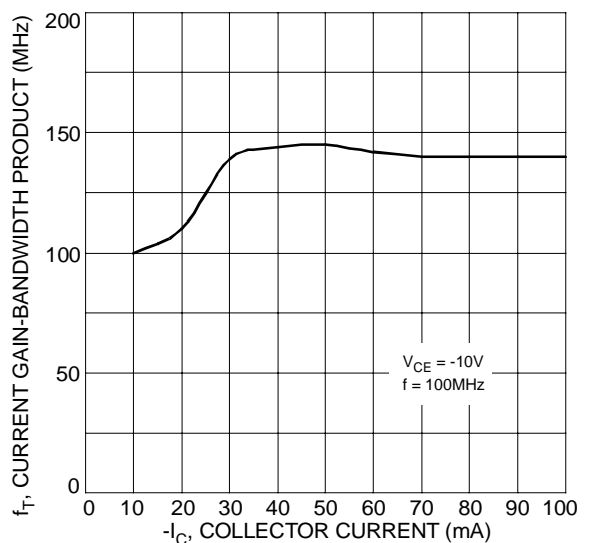


Fig. 8 Typical Gain-Bandwidth Product vs. Collector Current



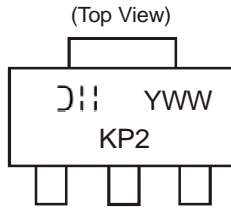
NEW PRODUCT

Ordering Information (Note 6)

Device	Packaging	Shipping
DZT751-13	SOT-223	2500/Tape & Reel

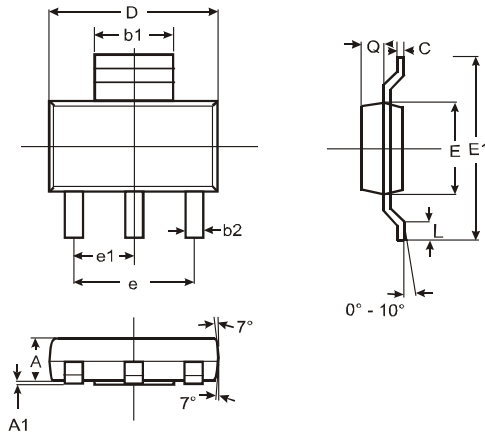
Notes: 6. For packaging details, please go to our website at <http://www.diodes.com/ap02007.pdf>.

Marking Information



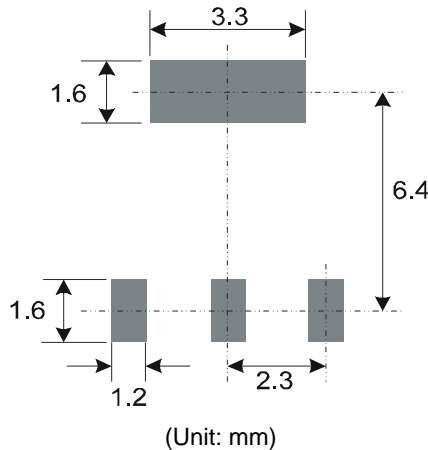
KP2 = Product Type Marking Code
 YWW = Date Code Marking
 Y = Last digit of year ex: 7 = 2007
 WW = Week code 01 - 52

Package Outline Dimensions



SOT-223			
Dim	Min	Max	Typ
A	1.55	1.65	1.60
A1	0.010	0.15	0.05
b1	2.90	3.10	3.00
b2	0.60	0.80	0.70
C	0.20	0.30	0.25
D	6.45	6.55	6.50
E	3.45	3.55	3.50
E1	6.90	7.10	7.00
e	—	—	4.60
e1	—	—	2.30
L	0.85	1.05	0.95
Q	0.84	0.94	0.89
All Dimensions in mm			

Suggested Pad Layout



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